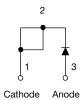


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Vishay Semiconductors

Fast Soft Recovery Rectifier Diode, 20 A





| PRODUCT SUMMARY | | | | |
|----------------------------------|---------------------|--|--|--|
| Package | TO-220FP | | | |
| I _{F(AV)} | 20 A | | | |
| V _R | 200 V, 400 V, 600 V | | | |
| V _F at I _F | 1.3 V | | | |
| I _{FSM} | 300 A | | | |
| t _{rr} | 60 ns | | | |
| T _J max. | 150 °C | | | |
| Diode variation | Single die | | | |
| Snap factor | 0.6 | | | |

FEATURES

- · Glass passivated pellet chip junction
- 150 °C max. operation junction temperature
- Designed and qualified according to JEDEC®-JESD 47
- Fully isolated package (V_{INS} = 2500 V_{RMS})
- UL E78996 approved
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912





ROHS COMPLIANT HALOGEN FREE

APPLICATIONS

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

DESCRIPTION

The VS-20ETF0..FP... fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

| MAJOR RATINGS AND CHARACTERISTICS | | | | | |
|-----------------------------------|------------------------------|-------------|-------|--|--|
| SYMBOL | CHARACTERISTICS | VALUES | UNITS | | |
| I _{F(AV)} | Sinusoidal waveform | 20 | A | | |
| V _{RRM} | | 200 to 600 | V | | |
| I _{FSM} | | 300 | A | | |
| V _F | 10 A, T _J = 25 °C | 1.2 | V | | |
| t _{rr} | 1 A, 100 A/µs | 60 | ns | | |
| T _J | | -40 to +150 | °C | | |

| VOLTAGE RATINGS | | | | | |
|----------------------------------|---|--|-------------------------------------|--|--|
| PART NUMBER | V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V | V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V | I _{RRM} AT 150 °C mA | | |
| VS-20ETF02FPPbF, VS-20ETF02FP-M3 | 200 | 300 | | | |
| VS-20ETF04FPPbF, VS-20ETF04FP-M3 | 400 | 500 | 5 | | |
| VS-20ETF06FPPbF, VS-20ETF06FP-M3 | 600 | 700 | | | |

| ABSOLUTE MAXIMUM RATINGS | | | | | |
|---------------------------------------|------------------------|--|--------|-------------------|--|
| PARAMETER | SYMBOL TEST CONDITIONS | | VALUES | UNITS | |
| Maximum average forward current | I _{F(AV)} | T _C = 51 °C, 180° conduction half sine wave | 20 | | |
| Maximum peak one cycle non-repetitive | I | 10 ms sine pulse, rated V _{RRM} applied | 250 | Α | |
| surge current | IFSM | 10 ms sine pulse, no voltage reapplied | 300 | | |
| Maximum I ² t for fusing | l ² t | 10 ms sine pulse, rated V _{RRM} applied | 316 | A ² s | |
| Maximum i-t for fusing | | 10 ms sine pulse, no voltage reapplied | 442 | A-5 | |
| Maximum I ² √t for fusing | I²√t | t = 0.1 ms to 10 ms, no voltage reapplied | 4420 | A ² √s | |



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| ELECTRICAL SPECIFICATIONS | | | | | |
|---------------------------------|--------------------|------------------------------|---|--------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | VALUES | UNITS |
| Mariana for an all and a durant | | 20 A, T _J = 25 °C | | 1.30 | V |
| Maximum forward voltage drop | V_{FM} | 60 A, T _J = 25 °C | 1.67 | | V |
| Forward slope resistance | r _t | T _J = 150 °C | | 12.5 | mΩ |
| Threshold voltage | V _{F(TO)} | T _J = 150 °C | | 0.9 | V |
| Maximum reverse leakage current | I _{RM} | T _J = 25 °C | V _R = Rated V _{RRM} | 0.1 | mA |
| | | T _J = 150 °C | | 5.0 | |

| RECOVERY CHARACTERISTICS | | | | | |
|--------------------------|-----------------|--------------------------------------|--------|-------|----------------------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | • |
| Reverse recovery time | t _{rr} | I _F at 20 A _{pk} | 160 | ns | I _{FM} † |
| Reverse recovery current | I _{rr} | 100 A/μs | 10 | Α | $t_a \mid t_b$ |
| Reverse recovery charge | Q _{rr} | 25 °C | 1.25 | μC | dir/ dt Q _{rr} |
| Snap factor | S | Typical | 0.6 | | I _{RM(REC)} |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | |
|--|-----------|-----------------------------------|---------------------------------------|-------------|------------------|--|
| PARAMETER | | SYMBOL | TEST CONDITIONS | VALUES | UNITS | |
| Maximum junction and temperature range | l storage | T _J , T _{Stg} | | -40 to +150 | °C | |
| Maximum thermal resignation to case | stance, | R_{thJC} | DC operation | 2.5 | | |
| Maximum thermal resist junction to ambient | stance, | R_{thJA} | | 62 | °C/W | |
| Typical thermal resista case to heatsink | nce, | R _{thCS} | Mounting surface, smooth, and greased | 0.5 | | |
| Approximate weight | | | | 2 | g | |
| Approximate weight | | | | 0.07 | oz. | |
| Mounting torque | minimum | | | 6 (5) | kgf ⋅ cm | |
| Wounting torque | maximum | | | 12 (10) | (lbf \cdot in) | |
| | | | | 20ETF | 02FP | |
| Marking device | | | Case style TO-220 FULL-PAK | 20ETF | TF04FP | |
| | | | | 20ETF | 06FP | |

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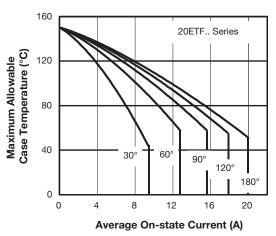


Fig. 1 - Current Rating Characteristics

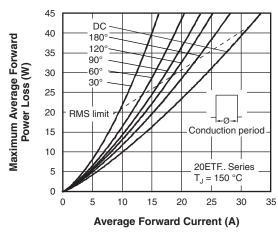


Fig. 4 - Forward Power Loss Characteristics

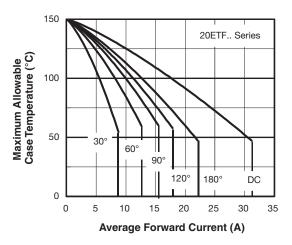


Fig. 2 - Current Rating Characteristics

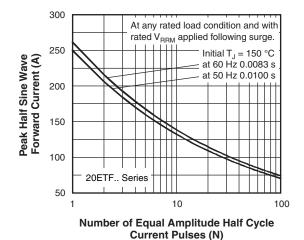


Fig. 5 - Maximum Non-Repetitive Surge Current

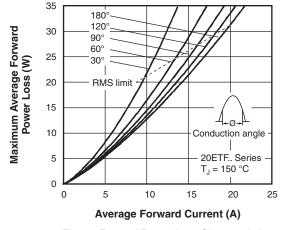


Fig. 3 - Forward Power Loss Characteristics

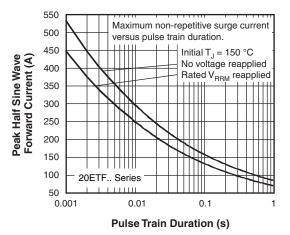


Fig. 6 - Maximum Non-Repetitive Surge Current





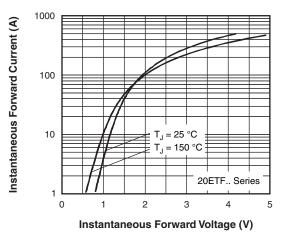


Fig. 7 - Forward Voltage Drop Characteristics

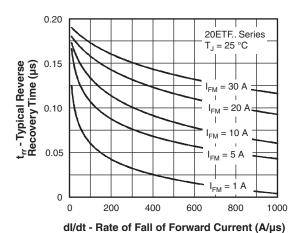


Fig. 8 - Recovery Time Characteristics, T_J = 25 °C

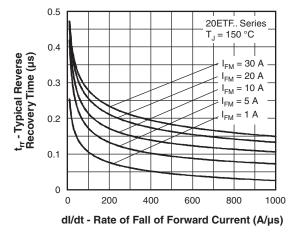
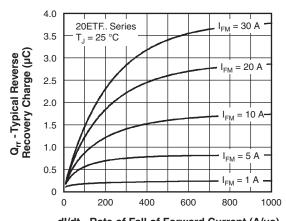


Fig. 9 - Recovery Time Characteristics, T_J = 150 °C



dl/dt - Rate of Fall of Forward Current (A/ μ s) Fig. 10 - Recovery Charge Characteristics, T_J = 25 °C

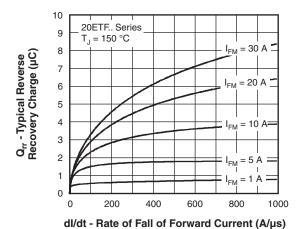
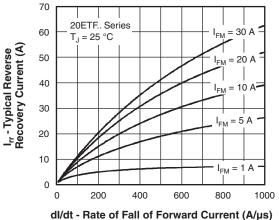


Fig. 44 Bases of Observation Fig. 450





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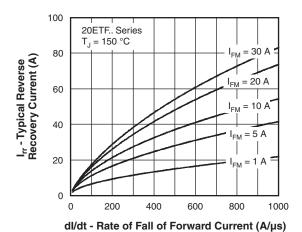


Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

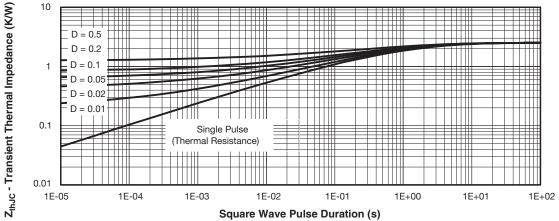
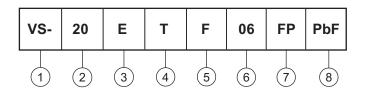


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

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ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

Current rating (20 = 20 A)

Circuit configuration:

E = single diode

Package:

T = TO-220

5 Type of silicon:

F = fast soft recovery rectifier

02 = 200 V Voltage code x $100 = V_{RRM}$ 04 = 400 V

06 = 600 V

FULL-PAK

Environmental digit:

• PbF = lead (Pb)-free and RoHS-compliant

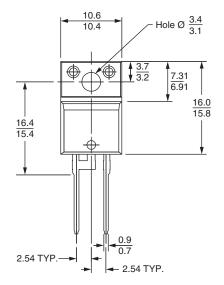
• -M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

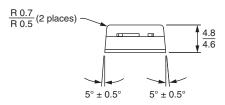
| ORDERING INFORMATION (Example) | | | | | |
|--------------------------------|------------------|------------------------|--------------------------|--|--|
| PREFERRED P/N | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | |
| VS-20ETF02FPPbF | 50 | 1000 | Antistatic plastic tubes | | |
| VS-20ETF02FP-M3 | 50 | 1000 | Antistatic plastic tubes | | |
| VS-20ETF04FPPbF | 50 | 1000 | Antistatic plastic tubes | | |
| VS-20ETF04FP-M3 | 50 | 1000 | Antistatic plastic tubes | | |
| VS-20ETF06FPPbF | 50 | 1000 | Antistatic plastic tubes | | |
| VS-20ETF06FP-M3 | 50 | 1000 | Antistatic plastic tubes | | |

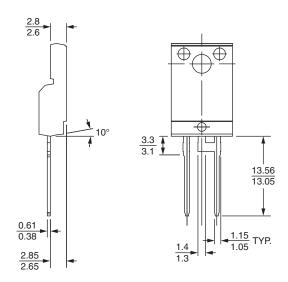
| LINKS TO RELATED DOCUMENTS | | | | |
|--|---------------|--------------------------|--|--|
| Dimensions <u>www.vishay.com/doc?95005</u> | | | | |
| Deut as addis a información | TO-220 FP PbF | www.vishay.com/doc?95009 | | |
| Part marking information | TO-220 FP -M3 | www.vishay.com/doc?95440 | | |
| SPICE model | | www.vishay.com/doc?95410 | | |

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DIMENSIONS in millimeters







Lead assignments

Diodes

1 + 2 - Cathode

3 - Anode

Conforms to JEDEC outline TO-220 FULL-PAK



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